Material Declaration Data Sheets. AMD has created material data sheets for some of its more popular package designs. These data sheets are organized as follows:

- Suface-Mount Array Packages
 - PBGA & LFBGA, page 2-19
- Surface-Mount Leaded Packages
 - PLCC, *page 20-25*
 - PQFP,TQFP, page 26-44

Material Declaration Sheet

Package Type: 208 PBGA Description: Semiconductor (Geode Products) Average Weight: 1.74 grams Contact: jim.casto@amd.com

The following materials are contained in products using this package:

ltem	Component	% of component in item	Wt of Item (mg)	Wt. of component (mg)	ppm of component in package
Substrate	BT	43.00	430.52	185.13	106,302
	Cu	40.67		175.09	100,542
	Ni	2.0940		9.02	5,177
	Au	0.2270		0.98	561
	Solder Mask	14.00		60.27	34,610
Plastic	SiO2	86.70	881.93	764.63	439,061
	ECN	12.00		105.83	60,770
	Sb2O3	0.9		7.94	4,558
	Br	0.4		3.53	2,026
Chip	Si	99.4	19.33	19.21	11,031
	Al	0.6		0.12	67
Die Attach	Ag	75	1.94	1.46	836
	bismaleimide	25		0.49	279
Wires	Au	100	5.96	5.96	3,420
Solder Balls	Sn	63	401.88	253.18	145,381
	Pb	37		148.69	85,382
	•	•		1741.51	1,000,000

Notes

Component	Chemical Name
BT	Bismaleimide triazine
Solder Mask	Unknown
ECN	Epoxy cresol novalac resin
Br	Brominated flame retardant; part of cured epoxy matrix in final product.



Package:	PBGA, BGA 272	Average Weight:	2.4 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest Reference ¹		Description of Use	Concentration	
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 6,000 PPM	
Brominated Polymers	C2c	Brominated Polymer in Molding Compound	< 2.5%	
Copper	C1k	Traces within substrate	< 7.5 wt%	
Gold	C1I	Wire Bonding and Internal Plating	< 800 PPM	
Nickel	C1h	Internal Plating	< 3,500 PPM	
Pb (Lead)	C1f	Solder Balls	< 8.5 wt%	
Silver	C1n	Die Attach	< 5,500 PPM	

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration	
Amines	< 200 PPM	Silica (Quartz)	< 2,000 PPM	
BT Resin	< 1.5 wt %	Silicon	< 2.0 wt%	
Carbon Black	< 2,000 PPM	SiO2 Filler (Fused Silica)	< 24.0 wt %	
Chlorine	< 1,000 PPM	SiO2 Glass Mesh	< 19.0 wt %	
Ероху	< 4 wt %	Solder Mask	< 4.5 wt %	
Phenol, Polymer with Formaldehyde	< 3.5 wt %	Tin	< 14.0 wt %	
Silica (Christobalite)	< 2,000 PPM			



Package:	PBGA, LBB 324	Average Weight:	1.3 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 7,000 PPM
Copper	C1k	Leads	< 9.5%
Gold	C1I	Wire Bonding	< 1%
Nickel	C1h	Leads	< 1.6%
Pb (Lead)	C1f	Leads	< 5.3%
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,300 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Material Declaration Sheet

Package Type: 352 PBGA Description: Semiconductor (Geode Products)

Average Weight: 4.25 grams Contact: james.casto@amd.com

The following materials are contained in products using this package:

ltem	Component	% of component in item	Wt of Item (mg)	Wt. of component (mg)	ppm of component in package
Substrate	BT	60.85	1,420.02	864.08	203,335.94
	Cu	27.77		394.37	92,802.72
	Ni	1.269		18.02	4,240.48
	Au	0.138		1.96	461.14
	Solder Mask	9.97		141.59	33,319.03
Plastic	SiO2	86.70	2,080.99	1,804.22	424,570.37
	ECN	12.00		249.72	58,764.06
	Sb2O3	0.9		18.73	4,407.30
	Br	0.4		8.32	1,958.80
Chip	Si	99.4	53.14	52.82	12,428.76
	Al	0.6		0.32	75.02
Die Attach	Ag	75	5.20	3.90	917.41
	bismaleimide	25		1.30	305.80
Wires	Au	100	10.08	10.08	2,371.53
Solder Balls	Sn	63	680.10	428.46	100,826.22
	Pb	37		251.64	59,215.40
		•		4,249.52	1,000,000.00

Component	Chemical Name		
вт	Bismaleimide triazine		
Solder Mask	Unknown		
ECN	Epoxy cresol novalac resin		
Br	Brominated flame retardant; part of cured epoxy matrix in final product.		

Material Declaration Sheet

Package Type: 388 TEPBGA **Description:** Semiconductor (Geode Products) Average Weight: 5.37 grams Contact: jim.casto@amd.com

The following materials are contained in products using this package:

ltem	Component	% of component in item	Wt of Item (mg)	Wt. of component (mg)	ppm of component in package
Substrate	BT	25.23	2562.64	646.56	120283
	Cu	68.61		1758.23	327096
	Ni	0.515		13.20	2455
	Au	0.070		1.79	334
	Solder Mask	5.57		142.74	26555
Plastic	SiO2	86.7	1963.70	1702.52	316732
	ECN	12		235.64	43838
	Sb2O3	0.9		17.67	3288
	Br	0.4		7.85	1461
Chip	Si	99.4	83.58	83.08	15456
	Al	0.6		0.50	93
Die Attach	Ag	75	8.11	6.08	1132
	Epoxy Resin	25		2.03	377
Wires	Au	100	7.71	7.71	1435
Solder Balls	Sn	63	749.66	472.28	87862
	Pb	37		277.37	51602
L.		L		5375	1,000,000

Component	Chemical Name
BT	Bismaleimide triazine
Solder Mask	Unknown
ECN	Epoxy cresol novalac resin
Br	Brominated flame retardant; part of cured epoxy matrix in final product.

Package: PBGA, LBB 324 (continued)

Additional Information/Additional Materials

Material	Concentration	Material	Concentration	
Amines, Aliphatic	< 250 PPM	Other Halogenated Aromatic Compounds	< 3,500 PPM	
		Oxides and Hydroxides (except for C, Si, Fe, Al, Ti, Mn, Mg, and Ca)	< 7,000 PPM	
Aromatic Compounds as Monomers	< 25 PPM	Phenol and Phenolic Compounds as Monomers	< 25 PPM	
BT Resin	< 9%	Phosphorus Compounds (except for Al, Ca, Fe Phosphates)	< 1,400 PPM	
Carbon Black	< 2,600 PPM	Polybrominated Aromatic Compounds	< 3,000 PPM	
Chlorine	< 500 PPM	Silicon	< 2.8%	
Ероху	< 1.1%	SiO2 Filler	< 36%	
Halogenated Aromatic Hydrocarbons	< 3,500 PPM	SiO2 Glass Mesh	< 12%	
Organic Halogen Compounds	< 3,500 PPM	Solder Mask	< 6%	
Organic Oxygen Compounds	< 5.2%	Tin	< 9%	
Organic Silicon Compounds	< 7,000 PPM			



Package:	PBGA, LBA 399	Average Weight:	0.9 grams
Description:	Semiconductor	Contact:	james.cast@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest Reference ¹ Descriptio		Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 5,100 PPM
Copper	C1k	Leads	< 14.0%
Gold	C1I	Wire Bonding	< 1.0%
Nickel	C1h	Leads	< 2.3%
Pb (Lead)	C1f	Leads	< 4.2%
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,200 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Package: PBGA, LBA 399 (continued)

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Amines, Aliphatic	< 200 PPM	Other Halogenated Aromatic Compounds	< 2,600 PPM
Amines, Aromatic	< 200 PPM	Oxides and Hydroxides (except for C, Si, Fe, Al, Ti, Mn, Mg, and Ca)	< 5,100 PPM
Aromatic Compounds as Monomers	< 20 PPM	Phenol and Phenolic Compounds as Monomers	< 25 PPM
BT Resin	< 15%	Phosphorus Compounds (except for Al, Ca, Fe Phosphates)	< 1,100 PPM
Carbon Black	< 2,000 PPM	Polybrominated Aromatic Compounds	< 2,100 PPM
Chlorine	< 800 PPM	Silicon	< 2.3%
Ероху	< 7,200 PPM	SiO2 Filler	< 27%
Halogenated Aromatic Hydrocarbons	< 2,600 PPM	SiO2 Glass Mesh	< 18%
Organic Halogen Compounds	< 2,600 PPM	Solder Mask	< 4.0%
Organic Oxygen Compounds	< 3.8%	Tin	< 7.5%
Organic Silicon Compounds	< 5,500 PPM		



Package:	PBGA, LBA 424	Average Weight:	0.96 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 5,500 PPM
Copper	C1k	Leads	< 18.0%
Gold	C1I	Wire Bonding	< 1.2%
Nickel	C1h	Leads	< 3.0%
Pb (Lead)	C1f	Leads	< 4.0%
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,600 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Package: PBGA, LBA 424 (continued)

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Amines, Aliphatic	< 200 PPM	Other Halogenated Aromatic Compounds	< 2,800 PPM
Amines, Aromatic	< 200 PPM	Oxides and Hydroxides (except for C, Si, Fe, Al, Ti, Mn, Mg, and Ca)	< 5,500 PPM
Aromatic Compounds as Monomers	< 20 PPM	Phenol and Phenolic Compounds as Monomers	< 20 PPM
BT Resin	< 11%	Phosphorus Compounds (except for Al, Ca, Fe Phosphates)	< 1,100 PPM
Chlorine	< 600 PPM	Polybrominated Aromatic Compounds	< 2,300 PPM
Ероху	< 8,000 PPM	Silicon	< 3.2%
Halogenated Aromatic Hydrocarbons	< 2,800 PPM	SiO2 Filler	< 29%
Organic Halogen Compounds	< 2,800 PPM	SiO2 Glass Mesh	< 14%
Organic Oxygen Compounds	< 4.1%	Solder Mask	< 5.0%
Organic Silicon Compounds	< 5,500 PPM	Tin	< 7.0%



Package:	PBGA LBA424	Average Weight:	0.52 grams
Description:	Pb-free Alchemy Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Wt %	ppm	Mg
Antimony	C1a	Molding compound flame retardant	< 0.56	< 5,600	< 6.3
Compounds					
Bromine	C2c	Molding compound flame retardant	< 1.1	< 11,000	< 12.4
Copper	C1k	Internal circuitry	< 17.7	< 177,000	< 200
Gold	C1I	Wire bonding	< 1.2	< 12,000	< 13.6
Silver	C1n	External terminals (solder balls)	< 0.54	< 5,400	< 6.1

1. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2002). See "EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Ероху	< 0.79	< 7,900	< 8.9
BT Resin	< 10.1	< 101,000	< 114
Phosphorus Compounds	< 0.12	< 1,200	< 1.4
Organic Silicon compounds	< 0.56	< 5,600	< 6.3
Phosphorus	< 0.12	< 1,200	< 1.4
Silicon	< 3.1	< 31,000	< 35
SiO2 Filler (Fused Silica)	< 28.4	< 284,000	< 321
Tin	< 9.2	< 92,000	< 104
Carbon Black	< 0.21	< 2,100	< 2.4
Nickel	< 2.9	< 29,000	< 33
Silica	< 0.38	< 3,800	< 4.2
SiiO2 Glass Mesh	< 13.4	< 134,000	< 151.4
Solder Mask	< 4.4	< 44,000	< 49.7
Organic Oxygen Compounds	< 4.1	< 41,000	< 46.3
Halogenated Aromatic Compounds	< 0.29	< 2,900	< 3.3
Organic Halogen Compounds	< 0.29	< 2,900	< 3.3
Other Halogenated Aromatic	< 0.29	< 2,900	< 3.3
Compounds			
Other Oxides and Hydroxides	< 0.56	< 5,600	< 6.3



Package:	PBGA BGA 388	Average Weight:	3.70 grams
Description:	Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Refer ence ⁱ	Description of Use	W t %	ppm	mg
Antimony Compounds	Cla	Molding compound flame retardant	< 0.23	< 2,265	< 8.3
Lead (Pb)	Clf	Solder ball	< 7.0	< 69,971	< 259.0
Copper	Clk	Substrate	< 3.8	< 138,052	< 511.0
Nickel	Clh	Substrate	< 0.63	< 6,267	< 23.2
Gold	CII	Wire bonding	< 0.71	< 7,100	< 26.1
Silver	Cln	Die attach	< 0.18	< I,847	< 6.8

I. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See "EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Ероху	< 7.98	< 79,707	< 295.0
Silicon	< 0.78	< 7,834	< 29.0
SiO2 Filler (Fused Silica)	< 33.26	< 332,567	< 1,231.0
Tin	< 11.94	< 9,4	< 442.0
Carbon Black	< 0.11	< I,I34	< 4.2
Silica	< 0.42	< 4,200	< 15.4
Mixed Siloxanes	< 0.76	< 7,600	< 28.0
Phenolic Resin	< 2.64	< 26,448	< 97.9
Acrylic	< 4.16	< 41,604	< 154.0
Bromine	< 0.04	< 405	< 1.5
Brominated Resin	< 0.76	< 7,556	< 28.0
Bisphenol	< 6.27	< 62,677	< 232.0
Triazol	< 8.35	< 83,479	< 309.0



Package:	PBGA BGA388	Average Weight:	3.78 grams
Description:	Pb-free Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference	Description of Use	Wt %	ppm	mg
Antimony Compounds	Cla	Molding compound flame retardant	< 0.04	< 4,000	< I.4
Gold	CII	Wire bonding	< 0.53	< 5,300	< 19.9
Silver	Cln	External terminals (solder balls) and die attach	< 0.83	< 8,300	< 31.4

I. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See "EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Ероху	< 7.01	< 70,050	< 264.8
Silicon	< 0.77	< 7,670	< 29.0
SiO2 Filler (Fused Silica)	< 64.38	< 643,800	< 2,433.0
Tin	< 19.74	< 197,368	< 746.1
Carbon Black	< 0.31	< 3,100	< 11.9
Silica	< 0.41	< 4,100	< 15.4
Mixed Siloxanes	< 0.74	< 7,400	< 28.0
Phenolic Resin	< 4.23	< 42,266	< 159.8
Metal Hydroxide	< 1.02	< 10,229	< 38.7



Package:	HSBGA BGU 396	Average Weight:	5.59 grams
Description:	Pb-free Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference	Description of Use	W t %	ppm	mg
Nickel	Clh	Substrate	< 0.55	< 5,535	< 31.0
Copper	Clk	Substrate and heat slug	< 43.95	< 429,501	< 2,402.2
Gold	CII	Wire bonding and substrate	< 0.62	< 6,204	< 34.7
Silver	Cln	Die attach and substrate	< 0.55	< 5,566	< 31.1

I. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See "EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Ероху	< 4.81	< 48,055	< 268.9
Silicon	< 0.75	< 7,474	< 41.8
SiO2 Filler (Fused Silica)	< 24.03	< 240,246	< I,343.7
Tin	< 12.37	< 123,667	< 691.7
Carbon Black	< 0.12	< I,250	< 7.0
Phenolic Resin	< 1.00	< I,004	< 56.0
Acrylic	< 2.77	< 27,677	< 154.8
Bisphenol	< 4.71	< 47,052	< 263.2
Triazol	< 4.15	< 41,516	< 232.2

Material Declaration Sheet

Package Type: 432L EBGA Description: Semiconductor (Geode Products) Average Weight: 10.87 grams Contact: james.casto@amd.com

The following materials are contained in products using this package:

ltem	Component	% of component in item	Wt of Item (mg)	Wt. of component (mg)	ppm of component in package
Substrate	BT	66.15	2268.22	1,500.40	138031
	Cu	29.56		670.42	61676
	Ni	0.0719		1.63	150
	Au	0.0224		0.51	47
	Solder Mask	4.20		95.26	8764
Heat Sink	Cu	99.38	7168.00	7,123.20	655308
	Ni	0.63		44.80	4121
Plastic	SiO2	73	455.55	332.55	30594
	ECN	23.5		107.05	9849
	Sb2O3	2.6		11.84	1090
	Br	0.9		4.10	377
Chip	Si	99.4	125.53	124.77	11479
	Al	0.6		0.75	69
Die Attach	Ag	75	9.71	7.28	670
	Epoxy Resin	25		2.43	223
Wires	Au	100	14.88	14.88	1369
Solder Balls	Sn	63	828.11	521.71	47996
	Pb	37		306.40	28188
	-	•		10,870.00	1,000,000

Component	Chemical Name
BT	Bismaleimide triazine
Solder Mask	Unknown
ECN	Epoxy cresol novalac resin
Br	Brominated flame retardant; part of cured epoxy matrix in final product.

Material Declaration Sheet

Package Type: 481 TEPBGA **Description:** Semiconductor (Geode Products) Average Weight: 8.58 grams Contact: jim.casto@amd.com

The following materials are contained in products using this package:

Item	Component	% of component in item	Wt of Item (mg)	Wt. of component (mg)	ppm of component in package
Substrate	BT	25.32	3,339.40	845.64	98,493.88
	Cu	68.52		2,288.33	266,527.23
	Ni	0.458		15.30	1,782.04
	Au	0.062		2.08	241.78
	Solder Mask	5.63		188.06	21,904.06
Heat Spreader	Cu	98.63	1,900.00	1,873.99	218,268.01
	Cr	1.37		26.01	3,029.89
Plastic	SiO2	86.7	2,297.71	1,992.12	232,027.22
	ECN	12		275.73	32,114.49
	Sb2O3	0.9		20.68	2,408.59
	Br	0.4		9.19	1,070.48
Chip	Si	99.4	100.32	99.72	11,614.56
	Al	0.6		0.60	70.11
Die Attach	Ag	75	9.71	7.28	848.06
	Epoxy Resin	25		2.43	282.69
Wires	Au	100	9.56	9.56	1,113.87
Solder Balls	Sn	63	929.00	585.27	68,167.91
	Pb	37		343.73	40,035.12
	-	-		8,586	1,000,000

Component	Chemical Name	
вт	Bismaleimide triazine	
Solder Mask	Unknown	
ECN	Epoxy cresol novalac resin	
Br	Brominated flame retardant; part of cured epoxy matrix in final product.	



Package:	PBGA BGU481	Average Weight:	8.73 grams
Description:	Pb-free Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Refere nce1	Description of Use	Wt %	ppm	mg
		Substrate	<8.07	<80738	<704.87
Copper	C1k	Heat Slug	<36.32	<363243	<3171.26
Nickel	C1h	Substrate	< 0.29	<2853	<24.91
	CIII	Heat Slug	< 0.01	<146	<1.28
Gold	C11	Wire bonding	< 0.20	<1973	<17.23
	CII	Substrate	< 0.10	<1006	<8.78
Silver	C1n	Die attach	< 0.06	<628	<5.48
		Solder Ball	< 0.35	<3486	<30.43

1. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See " EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Epoxy	<4.17	<41,655	<363.7
Silicon	< 0.62	<6,191	<54.05
SiO2 Filler (Fused Silica)	<26.94	<269,394	<2,351.92
Tin	<9.61	<96,109	<839.07
Carbon Black	< 0.16	<1,604	<14.00
Silica	<2.15	<21,534	<188.00
Phenolic Resin	<1.44	<14,432	<126.00
Metal Hydroxide	< 0.64	<6,414	<56.00



Package:	PBGA, BGA 569	Average Weight:	5.2 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 5,000 PPM
Brominated Polymers	C2c	Brominated Polymer in Molding Compound	< 2.0%
Copper	C1k	Traces within substrate	< 12 wt%
Gold	C1I	Wire Bonding and Internal Plating	< 1,000 PPM
Nickel	C1h	Internal Plating	< 4,000 PPM
Pb (Lead)	C1f	Solder Balls	< 8.0 wt%
Silver	C1n	Die Attach	< 5,000 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration < 2,000 PPM	
Amines	< 200 PPM	Silica (Quartz)		
BT Resin	< 12.5 wt %	Silicon	< 2.0 wt%	
Carbon Black	< 1,600 PPM	SiO2 Filler (Fused Silica)	< 23 wt %	
Chlorine	< 750 PPM	SiO2 Glass Mesh	< 17 wt %	
Ероху	< 3.5 wt %	Solder Mask	< 7 wt %	
Phenol, Polymer with Formaldehyde			< 13.5 wt %	
Silica (Christobalite)	< 2,000 PPM			



Package:	PLCC, PL 020	Average Weight:	0.73 grams
Description:	Semiconductor	Conta ct:	james.casto @amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 1.9%
Brominated Polymers	C2c	Bromine Based Polymer	< 3,400 PPM
Copper	C1k	Leads	< 29.5%
Gold	C1I	Wire Bonding	< 1,100 PPM
Pb (Lead)	C1f	Leads	< 2,400 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 4,500 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 18%	Silicon	< 2.6%
Iron	< 7,400 PPM	Silicon Oxides	< 46%
Organic Phosphorous Compounds	< 2.5%	Tin	< 1.4%
Organic Silicon Compounds	< 2.5%	Zinc	< 400 PPM
Phosphorus	< 200 PPM		



Package:	PLCC, PL 028	Average Weight:	1.2 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2%
Brominated Polymers	C2c	Polymers in Molding Compound	< 4,000 PPM
Copper	C1k	Leads	< 26%
Gold	C1I	Wire Bonding	< 1,000 PPM
Pb (Lead)	C1f	Leads	< 2,100 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 3,900 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Ероху	< 19%	Silicon	< 2.6%
Iron	< 7,000 PPM	Silicon Oxides	< 49%
Organic Phosphorous Compounds	< 2,200 PPM	Tin	< 1.2%
Organic Silicon Compounds	< 2.7%	Zinc	< 300 PPM
Phosphorus	< 150 PPM		



Pac	kage:	PLCC, PL 032	
_		a	

Description: Semiconductor

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Average Weight: 1.1 grams

Contact: james.casto @amd.com

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 1.8%
Brominated Polymers	C2c	Polymers in Molding Compound	< 3,300 PPM
Copper	C1k	Leads	< 35%
Gold	C1I	Wire Bonding	< 2,000 PPM
Pb (Lead)	C1f	Leads	< 2,600 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 5,100 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 16.5%	Silicon	< 4.5%
Iron	< 8,500 PPM	Silicon Oxides	< 44%
Organic Phosphorous Compounds	< 2,000 PPM	Tin	< 1.5%
Organic Silicon Compounds	< 2.3%	Zinc	< 400 PPM
Phosphorus	< 200 PPM		



Package:	PLCC, PL 044	Average Weight:	2.4 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2.1%
Brominated Polymers	C2c	Polymers in Molding Compound	< 3,800 PPM
Copper	C1k	Leads	< 26%
Gold	C1I	Wire Bonding	< 1,000 PPM
Pb (Lead)	C1f	Leads	< 1,600 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 2,800 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 19%	Silicon	< 2%
Iron	< 6,500 PPM	Silicon Oxides	< 51%
Organic Phosphorous Compounds	< 2,300 PPM	Tin	< 9,000 PPM
Organic Silicon Compounds	< 2.7%	Zinc	< 300 PPM
Phosphorus	< 150 PPM		

X



Package:	PLCC, PL 068	Average Weight:	4.8 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2.2%
Brominated Polymers	C2c	Polymers in Molding Compound	< 4,100 PPM
Copper	C1k	Leads	< 19.5%
Gold	C1I	Wire Bonding	< 900 PPM
Pb (Lead)	C1f	Leads	< 1,200 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,300 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 20.3%	Silicon	< 8,000 PPM
Iron	< 5,000 PPM	Silicon Oxides	< 54%
Organic Phosphorous Compounds	< 2,400 PPM	Tin	<6,500 PPM
Organic Silicon Compounds	< 2.9%	Zinc	< 200 PPM
Phosphorus	< 100 PPM		



Package:	PLCC, PL 084	Average Weight:	7.3 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2.3%
Brominated Polymers	C2c	Polymers in Molding Compound	< 4,100 PPM
Copper	C1k	Leads	< 20%
Gold	C1I	Wire Bonding	< 600 PPM
Pb (Lead)	C1f	Leads	< 1,000 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,300 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 21%	Silicon	< 7,500 PPM
Iron	< 5,000 PPM	Silicon Oxides	< 54%
Organic Phosphorous Compounds	< 2,500 PPM	Tin	< 5,300 PPM
Organic Silicon Compounds	< 2.9%	Zinc	< 200 PPM
Phosphorus	< 100 PPM		



Package:	PQFP, PQR 044	Average Weight:	0.56 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2,500 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,300 PPM
Copper	C1k	Leads	< 31.5%
Gold	C1I	Wire Bonding	< 3,000 PPM
Pb (Lead)	C1f	Leads	< 400 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1%

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 7.5%	Silicon	< 5.5%
Iron	< 8,000 PPM	Silicon Oxides	< 53%
Organic Phosphorous Compounds	< 2,000 PPM	Tin	< 1.8%
Organic Silicon Compounds	< 5,000 PPM	Zinc and Zinc Compounds	< 750 PPM
Phosphorus	< 200 PPM		



Package:	PQFP, PQR 080	Average Weight:	1.8 grams
Description:	Semiconductor	Contact:	james.casto @amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 3,200 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,600 PPM
Copper	C1k	Leads	< 17.8%
Gold	C1I	Wire Bonding	< 1,850 PPM
Pb (Lead)	C1f	Leads	< 1,200 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 6,300 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 9.6%	Phosphorus	< 100 PPM
Iron	< 500 PPM	Silicon	< 5%
Organic Phosphorous Compounds	< 2,400 PPM	Silicon Oxides	< 69.5%
Organic Silicon Compounds	< 6,000 PPM	Tin	< 1.1%
Phenol and Phenolic Compounds as Monomers	< 50 PPM	Zinc and Zinc Compounds	< 400 PPM



Package:	PQFP, PQR 100	Average Weight:	1.9 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 3,200 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,600 PPM
Copper	C1k	Leads	< 18.9%
Gold	C1I	Wire Bonding	< 2,500 PPM
Pb (Lead)	C1f	Leads	< 1,300 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 5,700 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration	
Epoxy Concentration	< 9.3%	Silicon	< 4.5%	
Iron	< 4,700 PPM	Silicon Oxides	< 67.6%	
Organic Phosphorous Compounds	< 2,400 PPM	Tin	< 1.1%	
Organic Silicon Compounds	< 5,900 PPM	Zinc and Zinc Compounds	< 500 PPM	
Phenol and Phenolic Compounds as Monomers	< 40 PPM			



Package:	PQFP PQR 100 (Pb-free)	Average Weight:	1.60 grams
Description:	Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Refe renc e ¹	Description of Use	Wt %	ppm	mg
Copper	C1k	Leadframe and internal plating	<19.0	< 190,000	< 303.52
Nickel	C1h	Leadframe	< 0.59	< 5,910	< 9.45
Gold	C1I	Wire bonding	< 0.30	< 3,000	< 4.75
Silver	C1n	Die attach	< 0.15	< 1,500	< 2.36

1. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See " EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Epoxy Resin	< 6.14	< 61,400	< 98.1
Silicon	< 1.66	< 16,620	< 26.6
SiO2 Filler (Fused Silica)	< 65.0	< 650,000	< 1,038.0
Tin	< 1.79	< 17,900	< 28.5
Carbon Black	< 0.38	< 3,822	< 6.1
Magnesium	<0.03	< 300	< 0.5
t-Butylphenyl glycidyl ether	< 0.02	< 200	< 0.2
Phenolic Resin	< 4.97	< 49,700	< 79.5



Package:	PQFP, PRH 100	Average Weight:	1.9 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 3,100 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,600 PPM
Copper	C1k	Leads	< 19%
Gold	C1I	Wire Bonding	< 2,100 PPM
Pb (Lead)	C1f	Leads	< 1,300 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 6,500 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 9.1%	Silicon	< 5%
Iron	< 4,700 PPM	Silicon Oxides	< 66%
Organic Phosphorous Compounds	< 2,400 PPM	Tin	< 1.1%
Organic Silicon Compounds	< 5,800 PPM	Zinc and Zinc Compounds	< 600 PPM



Package:	PQFP, PQR 144	Average Weight:	5.9 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 3,600 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,800 PPM
Copper	C1k	Leads	< 12%
Gold	C1I	Wire Bonding	< 1,400 PPM
Pb (Lead)	C1f	Leads	< 700 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 2,400 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 10.5%	Silicon	< 1.6%
Iron	< 3,000 PPM	Silicon Oxides	< 75%
Organic Phosphorous Compounds	< 2,700 PPM	Tin	< 5,600 PPM
Organic Silicon Compounds	< 6,500 PPM	Zinc and Zinc Compounds	< 600 PPM
Phenol and Phenolic Compunds as Monomers	< 45 PPM		



Package:	PQFP, PQR 160	Average Weight:	5.8 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 1.8%
Brominated Epoxy Resin	C2c	Molding Compound	< 2.2%
Copper	C1k	Leads	< 13.5%
Gold	C1I	Wire Bonding	< 1,700 PPM
Pb (Lead)	C1f	Plating of Leads	< 800 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Leads	< 2,200 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Carbon Black	< 2,600 PPM	Phenolic Polymers	< 4.6%
Epoxy Concentration	< 8.7%	Silicon	< 1.6%
Iron	< 3,300 PPM	Silicon Oxides	< 75%
Organic Phosphorous Compounds	< 2,700 PPM	Tin	< 6,200 PPM
Organic Silicon Compounds	< 6,500 PPM	Zinc	< 140 PPM



Package:	PQFP, PQR 168	Average Weight:	5.8 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 4,000 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 5,600 PPM
Copper	C1k	Leads	< 10.2%
Gold	C1I	Wire Bonding	< 1,400 PPM
Pb (Lead)	C1f	Leads	< 850 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 2,500 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 10.4%	Silicon	< 1.8%
Iron	< 2,600 PPM	Silicon Oxides	< 76%
Organic Phosphorous Compounds	< 2,700 PPM	Tin	< 6,500 PPM
Organic Silicon Compounds	< 6,600 PPM	Zinc and Zinc Compounds	< 600 PPM

MATERIAL DECLARATION DATA SHEET

Package: PQL 176 (Plastic Quad Flat Package) Description: Semiconductor Average 1.9 grams Weight: Contact: James.Casto@amd.com

MATERIALS OF INTEREST

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template.

If so, please complete the following table.

Material of Interest	Appendix A Reference	Description of Use	Concentration
Antimony Trioxide	C1a	Molding compound flame retardant	< 7,600 PPM
Brominated Polymers	C2c	Molding compound polymer	< 4,600 PPM
Chromium	C1e	Leadframe	< 750 PPM
Copper	C1k	Leadframe	< 23 wt%
Gold	C1I	Wire Bonding	< 4,300 PPM
Organic Phosphorus Compounds	C2	Catalyst in molding compound	< 2,400 PPM
Pb (Lead)	C1f	Leadframe plating	< 1,300 PPM
Silver	C1n	Die attach and plating of internal leads	< 8,500 PPM

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material	Concentration
Epoxy	< 15 wt%
Organic silicon compounds	< 5,800 PPM
Phenol or phenolic monomer residue	< 40 PPM
Silicon	< 4.2 wt%
SiO ₂ filler	< 60 wt%
Tin	< 1.1 wt%
Zinc and zinc compounds	< 1,000 PPM



Package:	PQFP, PQR 208	Average Weight:	5.7 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 3,600 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,800 PPM
Copper	C1k	Leads	< 12.2%
Gold	C1I	Wire Bonding	< 2,300 PPM
Pb (Lead)	C1f	Leads	< 800 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 3,100 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration	
Epoxy Concentration	< 10.5%	Silicon	< 2.3%	
Iron	< 3,000 PPM	Silicon Oxides	< 77%	
Organic Phosphorous Compounds	< 2,800 PPM	Tin	< 6,500 PPM	
Organic Silicon Compounds	< 7,000 PPM	Zinc and Zinc Compounds	< 600 PPM	
Phenol and Phenolic Compounds as Monomers	< 50 PPM			



Package:	PQFP, PRH 208	Average Weight:	5.8 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide C1		Flame Retardant in Molding Compound	< 3,700 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 2,000 PPM
Copper	C1k	Leads	< 10.5%
Gold	C1I	Wire Bonding	< 2,500 PPM
Pb (Lead)	C1f	Leads	< 900 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1,500 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration	
Epoxy Concentration	< 10.5%	Silicon	< 7,000 PPM	
Iron	< 2,600 PPM	Silicon Oxides	< 77%	
Organic Phosphorous Compounds	< 2,700 PPM	Tin	< 6,100 PPM	
Organic Silicon Compounds	< 7,000 PPM	Zinc and Zinc Compounds	< 600 PPM	
Phenol and Phenolic Compounds as Monomers	< 50 PPM			



Package:	PQFP, PQB 132	Average Weight:	6.0 grams
Description:	Semiconductor	Contact:	james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide C1a Flame Retardant in Molding		Flame Retardant in Molding Compound	< 3,600 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 2,000 PPM
Copper	C1k	Leads	< 10.5%
Gold	C1I	Wire Bonding	< 1,600 PPM
Pb (Lead)	C1f	Leads	< 600 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 2,400 PPM

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Epoxy Concentration	< 10.5%	Silicon	< 1.8%
Iron	< 2,800 PPM	Silicon Oxides	< 77%
Organic Phosphorous Compounds	< 2,800 PPM	Tin	< 4,800 PPM
Organic Silicon Compounds	< 7,000 PPM	Zinc and Zinc Compounds	< 600 PPM



Package:	TQFP, PQT 044	Average Weight:	0.28 grams
Description:	Semiconductor	Contact:	larry.dungan@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2,800 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,400 PPM
Copper	C1k	Leads	< 34%
Gold	C1I	Wire Bonding	< 6,300 PPM
Pb (Lead)	C1f	Leads	< 2,200 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 2.5%

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Chromium	< 1,100 PPM	Silicon	< 8.5%
Epoxy Concentration	< 8.2%	Silicon Oxides	< 60%
Organic Phosphorous Compounds	< 2,200 PPM	Tin	< 1.9%
Organic Silicon Compounds	< 5,200 PPM	Zinc and Zinc Compounds	< 1,000 PPM
Phenol and Phenolic Compounds as Monomers	< 35 PPM		



Package:	TQFP, PQT 064	Average Weight:	0.30 grams
Description:	Semiconductor	Contact:	larry.dungan@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 \mathbf{X}

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest



The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Concentration
Antimony Trioxide	C1a	Flame Retardant in Molding Compound	< 2,300 PPM
Brominated Polymers	C2c	Polymers in Molding Compound	< 1,200 PPM
Copper	C1k	Leads	< 37%
Gold	C1I	Wire Bonding	< 7,500 PPM
Pb (Lead)	C1f	Leads	< 2,700 PPM
Silver	C1n	Heat Conduction Component of Die Attach, Plating of Internal Leads	< 1.5%

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2000). See "EIA Materials of Interest" on page Chapter 4-10 for a complete listing.

Additional Information/Additional Materials

Material	Concentration	Material	Concentration
Chromium	< 1,200 PPM	Silicon	< 7%
Epoxy Concentration	< 7%	Silicon Oxides	< 48%
Organic Phosphorous Compounds	< 1,800 PPM	Tin	< 2.5%
Organic Silicon Compounds	< 4,200 PPM	Zinc and Zinc Compounds	< 1,200 PPM
Phenol and Phenolic Compounds as Monomers	< 30 PPM		

Package:PQFP, PQT 080 (with SnPb Finish)Date Code:19 July 2004

Average Weight: 2.2 grams Contact: james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 $|\mathbf{X}|$

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Antimony Oxides	C1a	Mold Compound	< 26.4	< 12,000	< 1.2
Copper	C1k	Leadframe	< 405	< 184,000	< 18.4
Gold	C1I	Wire Bonds	< 4.0	< 1,800	< 0.18
Lead (Pb)	C1f	Solder Plating	< 2.0	< 900	< 0.090
Nickel	C1h	Internal Plating	< 12.8	< 5,800	< 0.58
Silver	C1n	Internal Plating	< 3.7	< 1,700	< 0.17

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2002).

Additional Information/Additional Materials

Material	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Amine resins	< 0.11	< 52	< 0.0052
Brominated Epoxy Resin	< 26.4	< 12,000	< 1.20
1,4-Butanedioldiglycidyl Ether	< 0.088	< 40	< 0.0040
Carbon Black	< 9.0	< 4,100	< 0.41
Ероху	< 143	< 65,000	< 6.5
Magnesium compounds	< 0.66	< 300	< 0.030
Phenolic polymer with formaldehyde	< 143	< 65,000	< 6.5
Silicon	< 13.6	< 6,200	< 0.62
SiO2 Filler	< 1,412	< 642,000	< 64.2
Tin	< 11.4	< 5,200	< 0.52

X

Package:PQFP, PQT 080 (Pb-free)Average Weight:2.2 gramsDate Code:19 July 2004Contact:james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Copper	C1k	Leadframe	< 396	< 180,000	< 0.18
Gold	C1I	Wire Bonds	< 4.4	< 2,000	< 0.002
Nickel	C1h	Internal Plating	< 13.2	< 6,000	< 0.006
Silver	C1n	Internal Plating	< 4.4	< 2,000	< 0.002

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2002).

Additional Information/Additional Materials

Material	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Acid anhydrides	< 0.022	< 10	< 0.0010
Amine resins	< 0.022	< 10	< 0.0010
Carbon Black	< 4.4	< 2,000	< 0.20
Ероху	< 90	< 41,000	< 4.1
Magnesium	< 0.66	< 300	< 0.030
Organic phosphorus compounds	< 9.0	< 4,100	< 0.41
Phenolic polymer with formaldehyde	< 90	< 41,000	< 4.1
Silicon	< 13	< 6,000	< 0.60
Silicone	< 14	< 6,500	< 0.65
SiO2 Filler	< 1,562	< 710,000	< 71.0
Tin	< 13	< 5,700	< 0.57

X



Package:	TQFP PQL I00 (Pb-free)	Average Weight:	0.73 grams
Description:	Semiconductor Device	Contact:	james.casto@amd.com

CONTROLLED MATERIALS

X The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

RESTRICTED MATERIALS

X The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

MATERIALS OF INTEREST

X The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Refer ence ^l	Description of Use	W t %	ppm	mg
Copper	Clk	Leadframe and external plating	<26.8	< 268,000	< 195.0
Nickel	Clh	Leadframe	< 0.83	< 8,300	< 6.1
Gold	Cll	Wire bonding	< 0.64	< 6,400	< 4.7
Silver	Cln	Die attach and internal plating	< 1.00	< 10,000	< 7.4

I. This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide

(February 2002). See "EIA Materials of Interest" on page 4-10 for a complete listing.

ADDITIONAL INFORMATION / ADDITIONAL MATERIALS

Material of Interest	wt %	ppm	mg
Epoxy Resin	< 4.71	< 47,100	< 34.3
Silicon	< 2.35	< 23,500	< 17.2
SiO2 Filler (Fused Silica)	< 58.20	< 582,000	< 423.8
Tin	< I.49	< 14,900	< 10.9
Carbon Black	< 0.20	< 2,000	< 1.5
Magnesium	<0.04	< 400	< 0.3
Acid Anhydrides	< 0.04	< 400	< 0.3
Phenolic Polymer	< 3.34	< 33,400	< 24.3
Phosphorus Compounds (as	< 0.37	< 3,700	< 2.7
Catalyst)			
Bismuth	<0.03	< 300	< 0.2

Package:PQFP, PQT 160 (Pb-free)Average Weight:5.7 gramsDate Code:19 July 2004Contact:james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Copper	C1k	Leadframe	< 713	< 125,000	< 12.5
Gold	C1I	Wire Bonds	< 8.6	< 1,500	< 0.15
Nickel	C1h	Internal Plating	< 26	< 4,500	< 0.45
Silver	C1n	Internal Plating	< 11.4	< 2,000	< 0.20

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2002).

Additional Information/Additional Materials

Material	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Al2O3	< 0.17	< 30	< 0.0030
Carbon Black	< 17	< 3,000	< 0.30
Ероху	< 428	< 75,000	< 7.5
Ester Resins	< 0.86	< 150	< 0.015
Magnesium	< 1.1	< 200	< 0.020
Organic phosphorus compounds	< 17	< 3,000	< 0.30
Phenolic polymer with formaldehyde	< 342	< 60,000	< 6.0
Silicon	< 74	< 13,000	< 1.3
SiO2 Filler	< 4,161	< 730,000	< 73.0
Tin	< 40	< 7,100	< 0.71

X

Package:PQFP, PQT 160 (with SnPb Finish)Date Code:19 July 2004

Average Weight: 5.7 grams Contact: james.casto@amd.com

Controlled Materials

The product neither contains nor was manufactured with materials listed in Section A of EIA's Material Declaration Template.

Restricted Materials



 $|\mathbf{X}|$

The product does not contain listed materials in prohibited applications indicated in Section B of EIA's Material Declaration Template.

Materials of Interest

The product <u>does</u> contain listed materials of interest as indicated by Section C of EIA's Material Declaration Template. These materials are listed in the following table.

Material of Interest	Reference ¹	Description of Use	Mass (mg)	Concentration (ppm)	Concentration (wt%)
Antimony Oxides	C1a	Mold Compound	< 103	< 18,000	< 1.8
Copper	C1k	Leadframe	< 713	< 125,000	< 12.5
Gold	C1I	Wire Bonds	< 8.6	< 1,500	< 0.15
Lead (Pb)	C1f	Solder Plating	< 6.3	< 1,100	< 0.11
Nickel	C1h	Internal Plating	< 26	< 4,500	< 0.45
Silver	C1n	Internal Plating	< 11	< 2,000	< 0.20

Note:

1 This reference corresponds to the item number of each material of interest as defined in Section C of EIA's Material Declaration Guide (February 2002).

Additional Information/Additional Materials

Material	Mass (mg)	Concentration (ppm)	Concentration (wt%)	
Brominated Epoxy Resin	< 125	< 22,000	< 2.2	
Butyrolacetone	< 0.40	< 70	< 0.0070	
Carbon Black	< 17	< 3,000	< 0.30	
Ероху	< 507	< 89,000	< 8.9	
Magnesium	< 1.4	< 250	< 0.025	
Organic phosphorus compounds	< 17	< 3,000	< 0.30	
Phenolic polymer with formaldehyde	< 257	< 45,000	< 4.5	
Silicon	< 74	< 13,000	< 1.3	
SiO2 Filler	< 3,876	< 680,000	< 68.0	
Tin	< 34	< 6,000	< 0.60	

X